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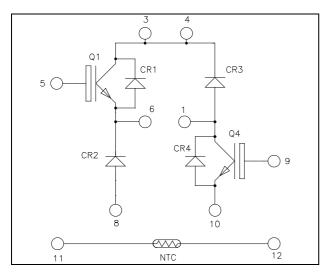


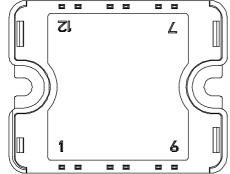


Asymmetrical - Bridge Trench + Field Stop IGBT3 Power Module

$$V_{CES} = 600V$$

 $I_{C} = 75A*$ @ $Tc = 80°C$





Pins 3/4 must be shorted together

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Very low stray inductance
 - Symmetrical design
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		600	V
Ţ	Continuous Collector Current	$T_C = 25^{\circ}C$	100*	
1 _C	I _C Continuous Collector Current	$T_C = 80^{\circ}C$	75*	Α
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	140	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25^{\circ}C$	250	W
RBSOA	Reverse Bias Safe Operating Area	$T_J = 150$ °C	150A @ 550V	

^{*} Specification of IGBT device but output current must be limited to 40A to not exceed a delta of temperature greater than 35°C for the connectors.

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				250	μA
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$ $T_j = 25^{\circ}C$			1.5	1.9	V
		$I_C = 75A$ $T_j = 150^{\circ}C$		1.7		v	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_{C} = 600 \mu A$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				600	nA

Dynamic Characteristics

·	Characteristic	Test Conditions	Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		4620		
Coes	Output Capacitance	$V_{CE} = 25V$		300		pF
C _{res}	Reverse Transfer Capacitance	f = 1MHz		140		1
Q_{G}	Gate charge	V_{GE} =±15V, I_{C} =75A V_{CE} =300V		0.8		μС
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)		110		ns
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$		45		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 300V$ $I_{\text{C}} = 75A$		200		
T_{f}	Fall Time	$R_G = 4.7\Omega$		40		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C $V_{GE} = \pm 15V$)	120		ns
T_{r}	Rise Time	$V_{\text{Bus}} = 300 \text{V}$		50		
$T_{d(off)}$	Turn-off Delay Time	$I_C = 75A$		250		
$T_{\rm f}$	Fall Time	$R_G = 4.7\Omega$		60		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $T_j = 25^{\circ}C$		0.35		mJ
Lon	Turn-on Switching Energy	$V_{\text{Bus}} = 300 \text{V}$ $T_{\text{j}} = 150$	C	0.6		1113
E_{off}	Turn-off Switching Energy	$I_{\rm C} = 75 {\rm A}$ $T_{\rm j} = 25 {\rm °C}$		2.2		mJ
Lott	Turn on Switching Energy	$R_G = 4.7\Omega$ $T_j = 150^{\circ}C$	C	2.6		1113
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; $V_{Bus} = 360V$ $t_p \le 6\mu s$; $T_i = 150^{\circ}C$		380		A

Diode ratings and characteristics (CR2 & CR3)

Symbol	Characteristic	,	Test Conditions		Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I_{RM}	Maximum Reverse Leakage Current	V _R =600V	$T_j = 25$ °C			250	μA
1 _{RM}	Waximum Reverse Leakage Current		$T_{j} = 150^{\circ}C$			500	μΛ
I_{F}	DC Forward current		$Tc = 80^{\circ}C$		75		A
V_{F}	Diode Forward Voltage	$I_F = 75A$	$T_i = 25^{\circ}C$		1.6	2	
, г	Block I of ward volume	$V_{GE} = 0V$	$T_{i} = 150^{\circ}C$		1.5		V
t _{rr}	Reverse Recovery Time		$T_j = 25$ °C		100		ns
·rr	reverse recovery Time	1 - 75 A	$T_{j} = 150^{\circ}C$		150		IIS
0	Payana Pagayany Changa	$\begin{split} I_F &= 75A \\ V_R &= 300V \\ di/dt &= 2000A/\mu s \end{split}$	$T_j = 25$ °C		3.6		μС
Q _{rr}	Reverse Recovery Charge		$T_{j} = 150^{\circ}C$		7.6		μС
г	В		$T_i = 25^{\circ}C$		0.85		m I
E_{r}	Reverse Recovery Energy		$T_{j} = 150^{\circ}C$		1.8		mJ

CR1 & CR4 are IGBT protection diodes only



Thermal and package characteristics

Symbol	Characteristic			Min	Typ	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance	IGBT			0.60	°C/W	
KthJC		Diode			0.98	C/ W	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		175	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					80	g

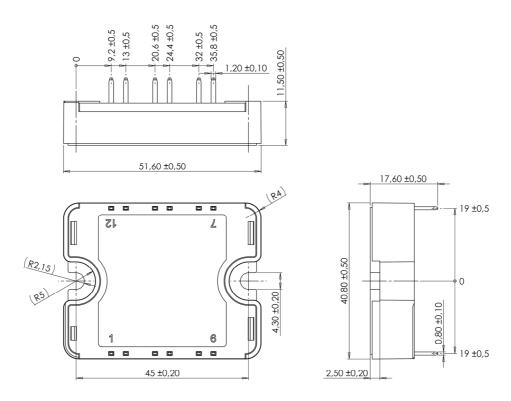
Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C	25°C		50		kΩ
$\Delta R_{25}/R_{25}$				5		%
B _{25/85}	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta \mathrm{B/B}$		T _C =100°C		4		%

$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{2c}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_{T}: \text{ Thermistor value at T}$$

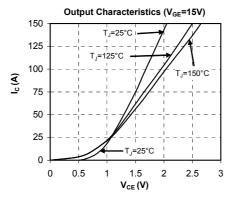
SP1 Package outline (dimensions in mm)

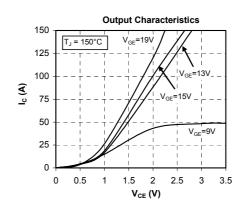


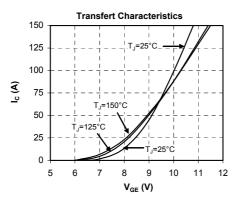
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

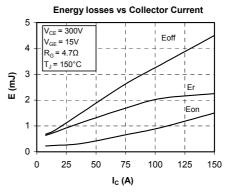


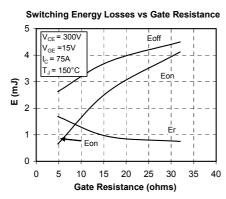
Typical Performance Curve

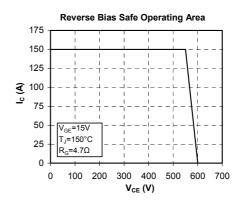


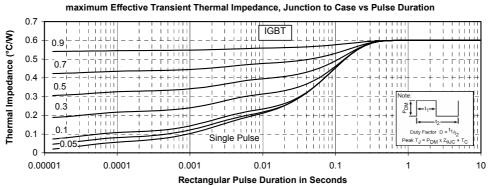




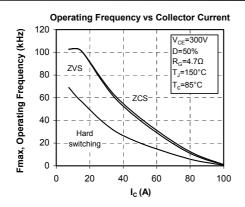


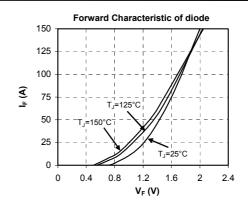


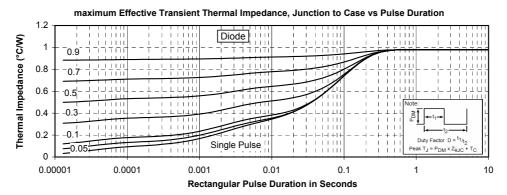












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